



#### N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
001/	25mΩ @ V <sub>GS</sub> = 10V	6.2A
30V	$28m\Omega @ V_{GS} = 4.5V$	5.8A

## **Features and Benefits**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMN3028LQ)

## **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Load Switch
- DC-DC Converters
- Power Management Functions

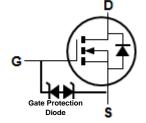
### **Mechanical Data**

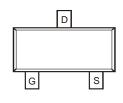
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208@3
- Terminal Connections: See Diagram
- Weight: 0.009 grams (Approximate)





SOT23





Top View

**Equivalent Circuit** 

Top View

## **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMN3028L-7	SOT23	3,000/Tape & Reel
DMN3028L-13	SOT23	10.000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# Marking Information



4N7 = Product Type Marking Code Y or  $\overline{Y}$  = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	G	Н	ı	J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	30	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	lo	6.2 4.9	А	
Pulsed Drain Current (380µs Pulse, Duty Cycle = 19	I <sub>DM</sub>	40	Α	
Maximum Body Diode Forward Current (Note 6)		Is	2	Α

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P <sub>D</sub>	0.86	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	146	°C/W
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	P <sub>D</sub>	1.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	88	°C/W
Thermal Resistance, Junction to Case (Note 6)		Rejc	13	C/VV
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

# $\textbf{Electrical Characteristics} \ (@T_A = +25 ^{\circ}\text{C}, \ unless \ \underline{otherwise \ specified.})$

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 7)								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$		
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	V <sub>DS</sub> = 24V, V <sub>GS</sub> = 0V		
Gate-Body Leakage	I <sub>GSS</sub>	_	_	±10	μA	$V_{GS} = \pm 16V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 7)								
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.8	_	1.8	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$		
Static Drain-Source On-Resistance	RDS(ON)	111	16 19 47	25 28 68	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 4.0A V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 3.5A V <sub>GS</sub> = 2.5V, I <sub>D</sub> = 2.5A		
Source-Drain Diode Forward Voltage	VsD	_	0.7	1.2	V	Vgs = 0V, Is = 1A		
DYNAMIC CHARACTERISTICS (Note 8)								
Input Capacitance	Ciss	_	680	_	pF			
Output Capacitance	Coss	1	96	_	pF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V f = 1.0MHz		
Reverse Transfer Capacitance	Crss	1	74	_	pF	1 - 1.011112		
Gate Resistance	Rg	1	1.7	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	1	10.9	_	nC			
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	1	7.8	_	nC	V <sub>DS</sub> = 15V, I <sub>D</sub> = 4A		
Gate-Source Charge	Qgs	1	1.6	_	nC	VDS = 15V, ID = 4A		
Gate-Drain Charge	$Q_{gd}$	1	4.8	_	nC			
Turn-On Delay Time	tD(ON)	1	6.7	_	ns			
Turn-On Rise Time	t <sub>R</sub>	-	1.5	_	ns	$V_{DD} = 15V, V_{GS} = 10V,$		
Turn-Off Delay Time	tD(OFF)	-	17.5	_	ns	$R_L = 15\Omega$ , $R_G = 6\Omega$		
Turn-Off Fall Time	t <sub>F</sub>	_	10.4	_	ns			

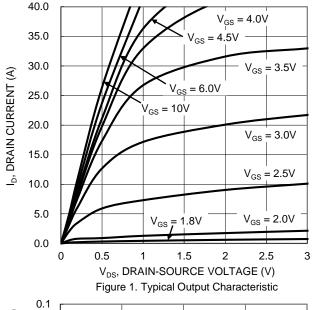
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

<sup>6.</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

<sup>7.</sup> Short duration pulse test used to minimize self-heating effect.

<sup>8.</sup> Guaranteed by design. Not subject to product testing.





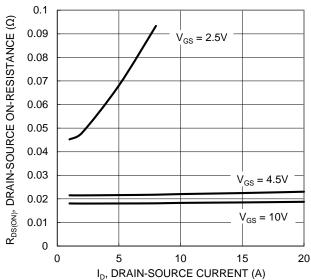


Figure 3. Typical On-Resistance vs. Drain Current

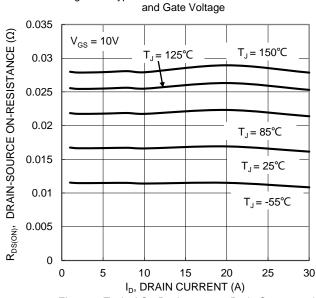
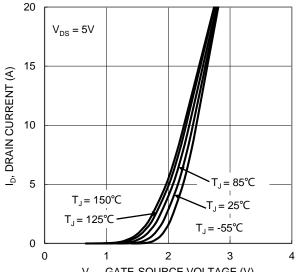


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature



 $V_{\text{GS}},$  GATE-SOURCE VOLTAGE (V) Figure 2. Typical Transfer Characteristic

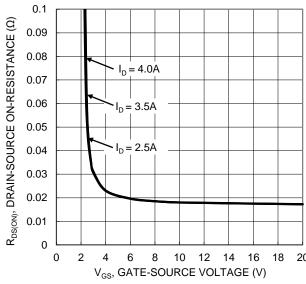


Figure 4. Typical Transfer Characteristic

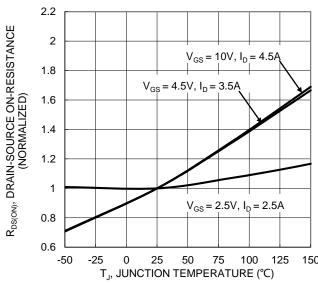


Figure 6. On-Resistance Variation with Junction Temperature





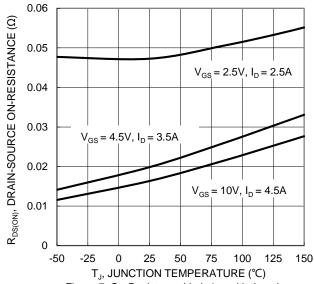


Figure 7. On-Resistance Variation with Junction Temperature

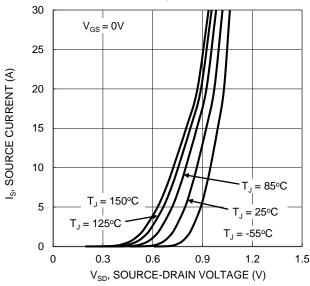


Figure 9. Diode Forward Voltage vs. Current

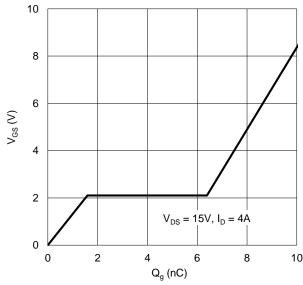


Figure 11. Gate Charge

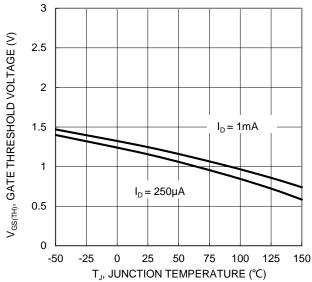


Figure 8. Gate Threshold Variation vs. Junction Temperature

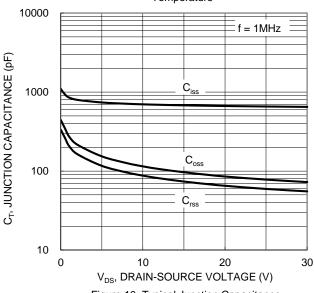
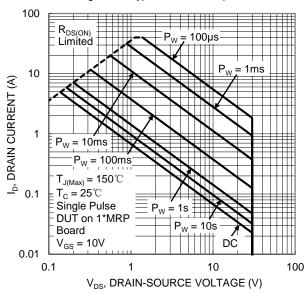


Figure 10. Typical Junction Capacitance





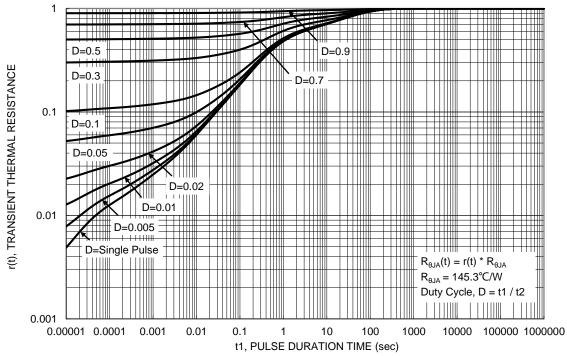


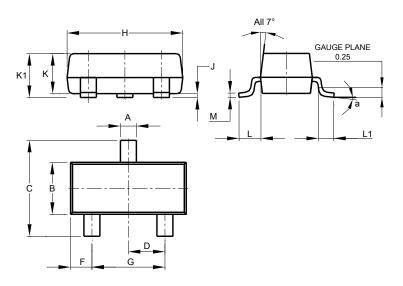
Figure 13. Transient Thermal Resistance



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23

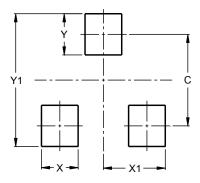


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
M	0.085	0.150	0.110				
а	0°	8°					
All Dimensions in mm							

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
V1	2.0

June 2020



#### **IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2020, Diodes Incorporated

www.diodes.com

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes Incorporated manufacturer:

Other Similar products are found below:

004419CB 069117AB 1.5KE15A-T 1.5KE15CA-T 1.5KE200A-T 1.5KE20CA-T 1.5KE24A-T 1.5KE250CA-T 1.5KE27CA-T 1.5KE30A-T 1.5KE30CA-T 1.5KE68CA-T 1.